

Product data sheet

1. General description

Planar passivated very sensitive gate four quadrant triac in a TO220 plastic package intended for use in general purpose bidirectional switching and phase control applications, where high sensitivity is required in all four quadrants. This very sensitive gate "series D" triac is intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

2. Features and benefits

- Direct triggering from low power drivers and logic ICs
- High blocking voltage capability
- · Low holding current for low current loads and lowest EMI at commutation
- · Planar passivated for voltage ruggedness and reliability
- Triggering in all four quadrants
- Very sensitive gate

3. Applications

- General purpose motor controls
- General purpose switching

4. Quick reference data

	uick reference data						
Symbol	Parameter	Conditions	Values			Unit	
Absolute	maximum rating						
V_{DRM}	repetitive peak off-state voltage			6	00		V
$I_{T(RMS)}$	RMS on-state current	full sine wave; T _{mb} ≤ 107 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	4			А	
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4; Fig. 5</u>	25			A	
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms		2	27		А
T _j	junction temperature		125				°C
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
I _{GT}	gate trigger current	V_{D} = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>		-	2	5	mA
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _i = 25 °C; <u>Fig. 7</u>		-	2.5	5	mA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 7}$	-	2.5	5	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G+};$ T _j = 25 °C; <u>Fig. 7</u>	-	5	10	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	1.2	10	mA
V _T	on-state voltage	I _T = 5 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.4	1.7	V
Dynamic	characteristics					
dV _D /dt	rate of rise of off-state voltage		-	5	-	V/µs

5. Pinning information

Table 2. Pinning information								
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	T1	main terminal 1						
2	T2	main terminal 2		T2T1				
3	G	gate		sym051				
mb	T2	mounting base; main terminal 2		Syntoon				

6. Ordering information

Table 3. Ordering information									
Type number	Package	Orderable part number	Packing	Small packing	Package	Package			
	Name		method	quantity	version	issue date			
BT136-600D	TO220	BT136-600D,127	Tube	50	TO220E	26-April-2019			

7. Marking

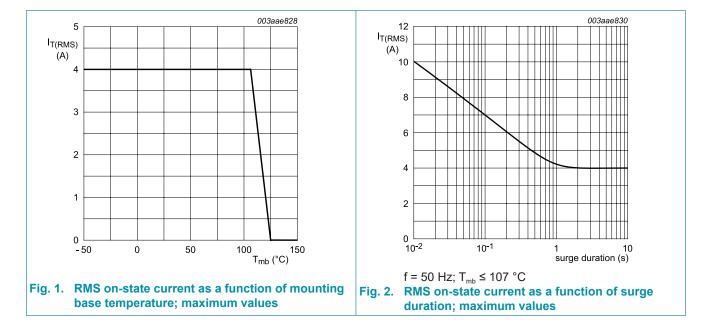
Table 4. Marking codes	
Type number	Marking codes
BT136-600D	BT136-600D

8. Limiting values

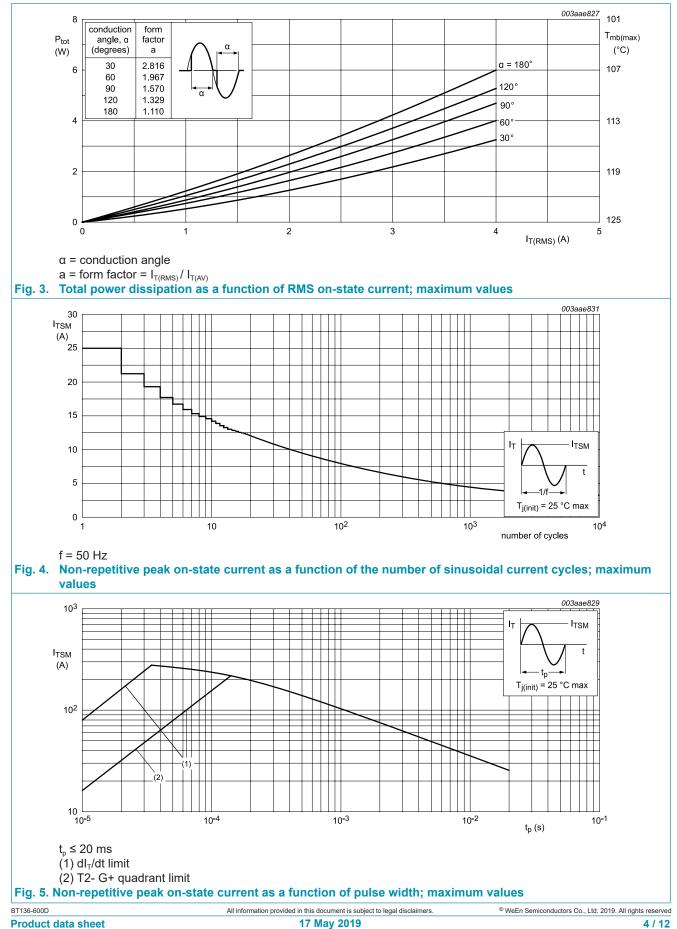
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{DRM}	repetitive peak off-state voltage		600	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 107 °C; <u>Fig 1; Fig 2; Fig 3</u>	4	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; Fig 4; Fig 5	25	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	27	А
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	3.1	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 10 mA; T2+ G+	50	A/µs
		I _G = 10 mA; T2+ G-	50	A/µs
		I _G = 10 mA; T2- G-	50	A/µs
		I _G = 20 mA; T2- G+	10	A/µs
I _{GM}	peak gate current		2	А
P _{GM}	peak gate power		5	W
P _{G(AV)}	average gate power	over any 20 ms period	0.5	W
T _{stg}	storage temperature		-40 to 150	°C
Tj	junction temperature		125	°C

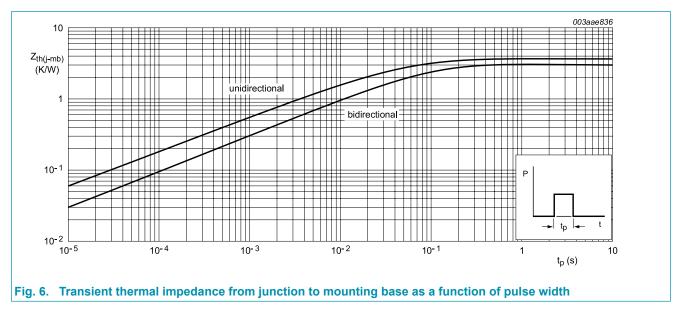


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9. Thermal characteristics

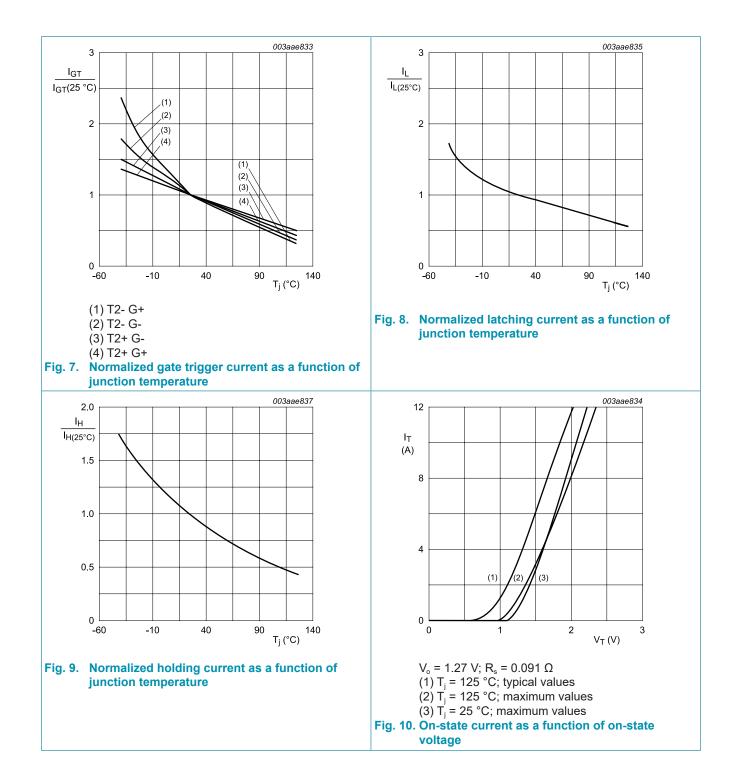
Table 6. Thermal characteristics								
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
$R_{th(j-mb)}$	thermal resistance	full cycle; <u>Fig 6</u>		-	-	3	K/W	
	from junction to mounting base	half cycle; <u>Fig 6</u>		-	-	3.7	K/W	
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air		-	60	-	K/W	

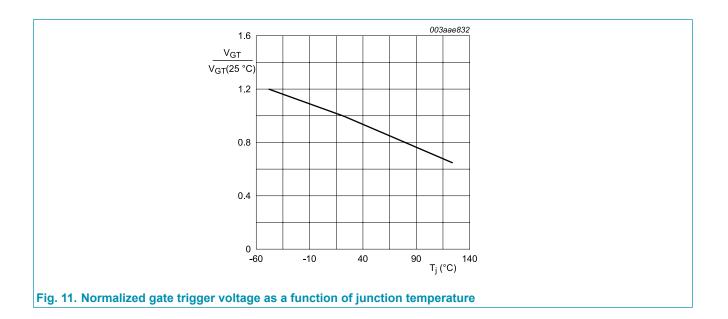


10. Characteristics

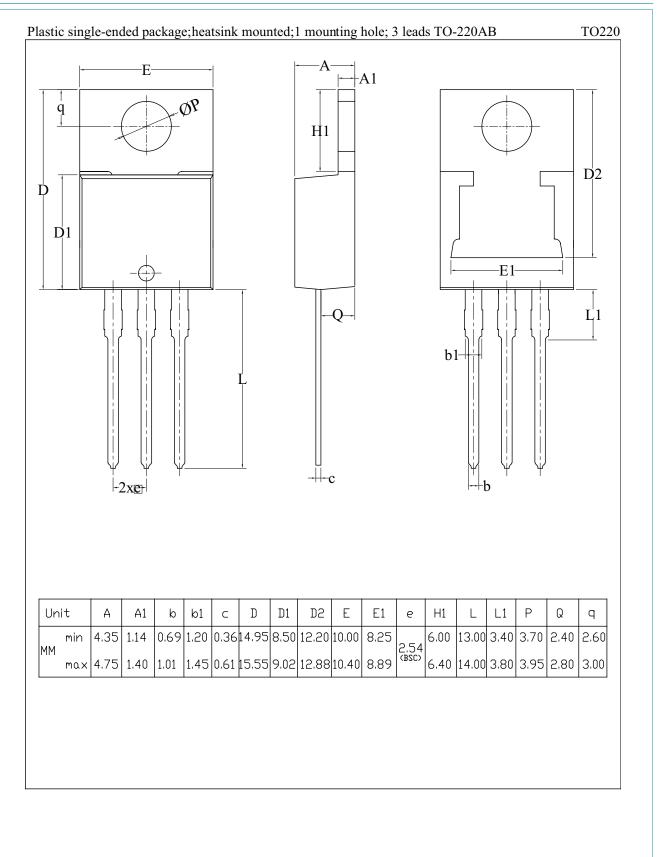
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ T2+ G+};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$	-	2	5	mA
		$V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 7}$	-	2.5	5	mA
		$V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}; \text{ T2- G-};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 7}$	-	2.5	5	mA
		V_{D} = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; Fig. 7	-	5	10	mA
IL	latching current	V_{D} = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 8</u>	-	1.6	10	mA
		V_{D} = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 8</u>	-	4.5	15	mA
		$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; <u>Fig. 8</u>	-	1.2	10	mA
		$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; \text{ T2- G+};$ T _j = 25 °C; <u>Fig. 8</u>	-	2.2	15	
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	1.2	10	mA
V _T	on-state voltage	$I_{T} = 5 \text{ A}; T_{j} = 25 \text{ °C}; Fig. 10$	-	1.4	1.7	V
V _{GT}	gate trigger voltage	$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T}_j = 25 \text{ °C};$ Fig. 11	-	0.7	1	V
		V _D = 400 V; I _T = 0.1 A; T _j = 125 °C	0.25	0.4	-	V
I _D	off-state current	V _D = 600 V; T _j = 125 °C	-	0.1	0.5	mA
Dynamic	characteristics	· · · · ·	I			
dV _D /dt	rate of rise of off-state voltage		-	5	-	V/µs
t _{gt}	gate-controlled turn-on time	$I_{TM} = 6 \text{ A}; V_D = 600 \text{ V}; I_G = 0.1 \text{ mA}; \text{ d}I_G/\text{ d}t = 5 \text{ A}/\mu\text{s}$	-	2	-	μs

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11. Package outline



12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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